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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Bao, et al.

Docket No:

TSM03-0927

Filed:

3/15/2004

Art Unit:

2818

Serial No.:

10/800,510

Examiner:

Tu-Tu Ho

For:

Semiconductor Device Having a Second Level of Metallization Formed over a

First Level with Minimal Damage to the First Level and Method

Mail Stop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

TRANSMITTAL OF REPLACEMENT FORMAL DRAWING

Dear Sir:

Submitted herewith is one replacement sheet of formal drawings for Figure 2g. This sheet replaces the informal drawing added by amendment on July 1, 2005, for the above-identified application.

Please contact Applicants' attorney with any questions regarding this matter.

Respectfully submitted,

Attorney of Record Reg. No. 35,361

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Applicant:

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March 15, 2004

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Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))

Date of Deposit:

January 12, 2006

I hereby certify that the below listed correspondence is being deposited with the United States Postal Service on the date indicated above as first class mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450.

Certificate of Mailing via First Class Mail (1 page) Transmittal of Replacement Formal Drawing (1 page) Replacement Formal Drawing Sheet (1 page) Return Postcard

Respectfully submitted,

Idalie Swider

Natalie Swider Legal Assistant

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